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# FQP15P12 / FQPF15P12 P-Channel QFET<sup>®</sup> MOSFET -120 V, -15 A, 0.2 Ω

## Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor®'s proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

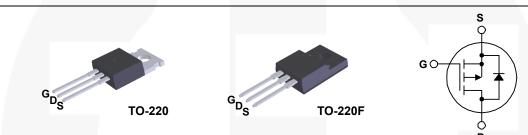
#### Features

- 15 A, -120 V,  $R_{DS(on)}$  = 0.2  $\Omega$  (Max.) @  $V_{GS}$  =-10 V,  $I_{D}$  = -7.5 A

FQP15P12 / FQPF15P12 P-Channel QFET<sup>®</sup> MOSFET

August 2014

- Low Gate Charge (Typ. 29 nC)
- Low Crss (Typ. 110 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating



### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

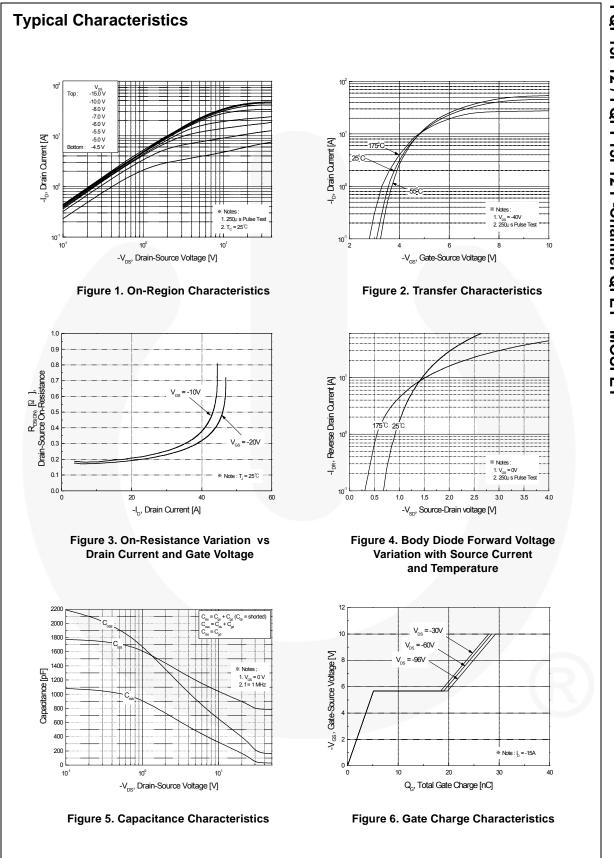
Drain-Source Voltage Drain Current - Continuous (T <sub>C</sub> = 25°C	.)	-1	20	V
	·)		-120	
	)	-15	-15 *	Α
- Continuous (T <sub>C</sub> = 100°C)		-10.6 *		A
Drain Current - Pulsed	(Note 1)	-60	-60 *	А
Gate-Source Voltage ± 30		30	V	
Single Pulsed Avalanche Energy	(Note 2)	1157		mJ
Avalanche Current	(Note 1)	-15		А
Repetitive Avalanche Energy	(Note 1)	10		mJ
Peak Diode Recovery dv/dt	(Note 3)	-5.0		V/ns
Power Dissipation ( $T_C = 25^{\circ}C$ )		100	41	W
- Derate above 25°C		0.67	0.27	W/°C
Operating and Storage Temperature Range		-55 to +175		°C
Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300		°C

#### Drain current nimited by maximum junction temperatur

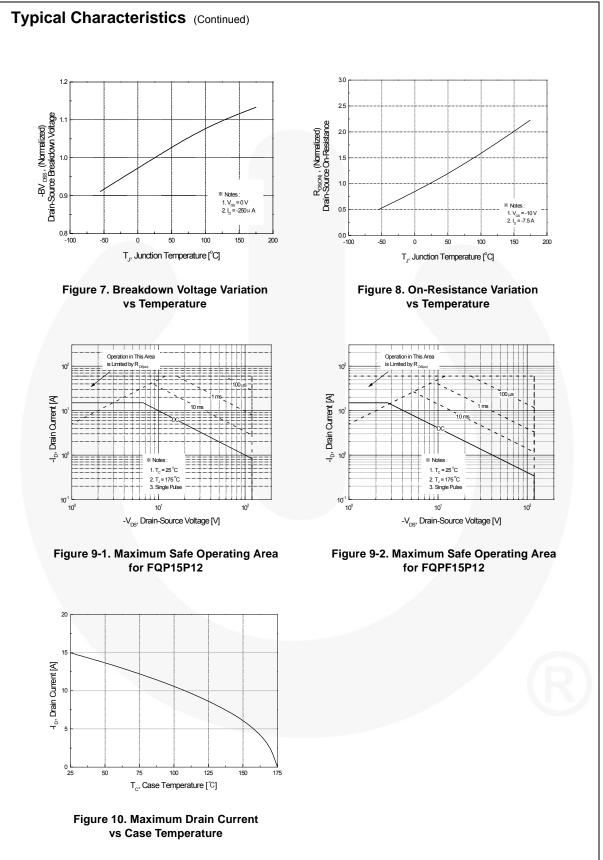
## **Thermal Characteristics**

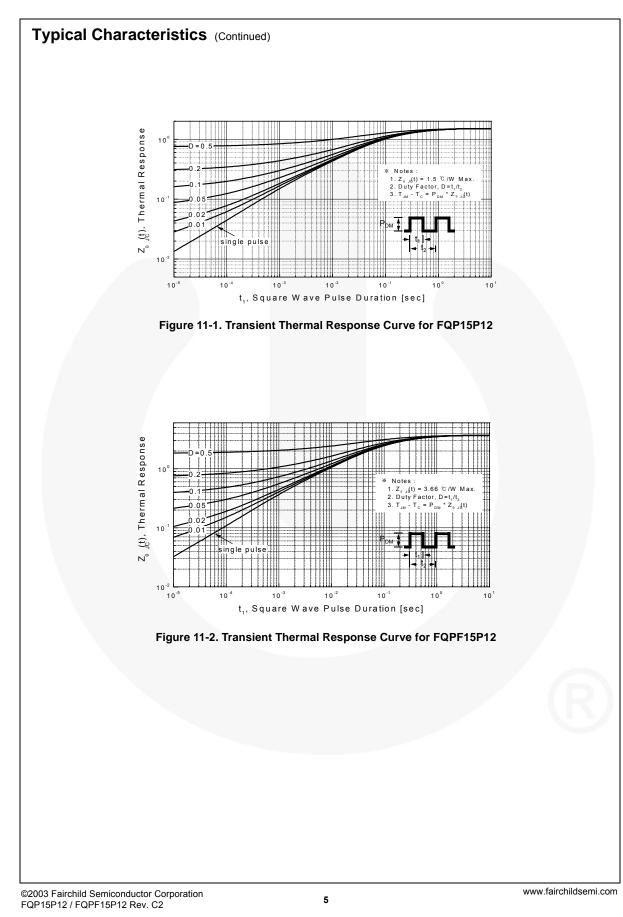
Symbol	Parameter	FQP15P12	FQPF15P12	Unit	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case	1.5	3.66	°C/W	
$R_{ extsf{ heta}JS}$	Thermal Resistance, Case-to-Sink Typ.	40		°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient	62.5	62.5	°C/W	

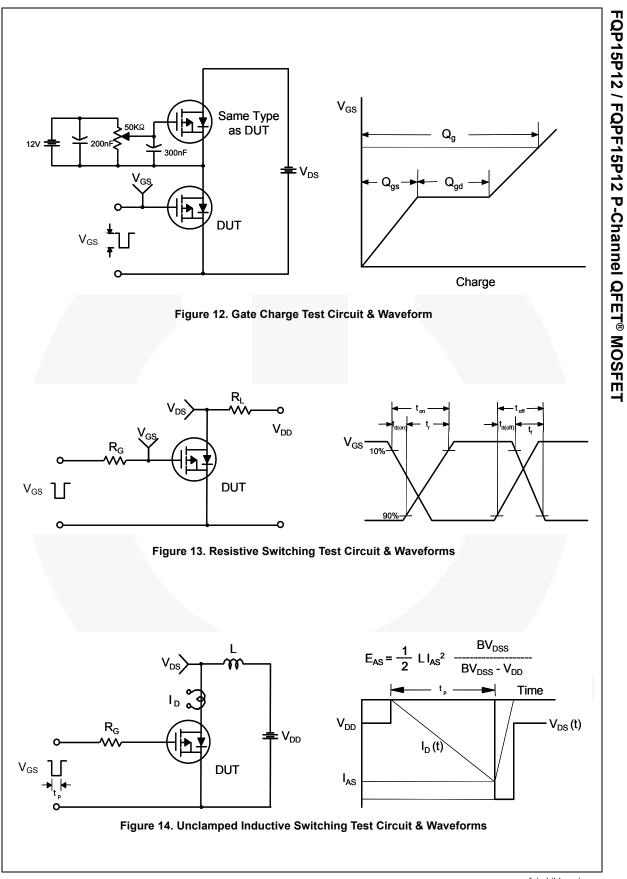
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	racteristics					
BV <sub>DSS</sub> Drain-Source Breakdown Voltage $V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		-120			V	
ΔBV <sub>DSS</sub> ΔΤJ	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu$ A, Referenced to 25°C		-0.13		V/°C
I <sub>DSS</sub>		V <sub>DS</sub> = -120 V, V <sub>GS</sub> = 0 V			-1	μA
	Zero Gate Voltage Drain Current $V_{DS} = -96 \text{ V}, T_C = 150^{\circ}\text{C}$				-10	μΑ
GSSF	Gate-Body Leakage Current, Forward	$V_{GS}$ = -30 V, $V_{DS}$ = 0 V			-100	nA
GSSR	Gate-Body Leakage Current, Reverse	$V_{GS}$ = 30 V, $V_{DS}$ = 0 V			100	nA
On Cha	racteristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	-2.0		-4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -7.5 \text{ A}$		0.17	0.2	Ω
Ĵfs	Forward Transconductance	V <sub>DS</sub> = -40 V, I <sub>D</sub> = -7.5 A		9.5		S
Dvnami	ic Characteristics		1			
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = -25 V, V <sub>GS</sub> = 0 V,		850	1100	pF
C <sub>oss</sub>	Output Capacitance	f = 1.0 MHz		310	400	, pF
Crss	Reverse Transfer Capacitance			110	140	pF
d(on)	ng Characteristics Turn-On Delay Time	V <sub>DD</sub> = -60 V, I <sub>D</sub> = -15 A,		15	40	ns
r	Turn-On Rise Time	$R_G = 25 \Omega$		100	210	ns
d(off)	Turn-Off Delay Time	(Note 4)		80	170	ns
f	Turn-Off Fall Time			80	170	ns
ე <sup>g</sup>	Total Gate Charge	$V_{DS} = -96 V, I_{D} = -15 A,$		29	38	nC
Q <sub>gs</sub>	Gate-Source Charge	$V_{GS} = -10 V$ (Note 4)		5.1		nC
ე <sub>gd</sub>	Gate-Drain Charge	(Note 4)		15		nC
	ource Diode Characteristics a	_				
S	Maximum Continuous Drain-Source Dic				-15	A
SM	Maximum Pulsed Drain-Source Diode F				-60	A
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_S = -15 A$			-4.0	V
	,					ns μC
$Q_{IT}$ <b>Detes:</b> Repetitive rat L = 6.0mH, I I <sub>SD</sub> ≤ -15A, c	Reverse Recovery Time Reverse Recovery Charge ating : pulse width limited by maximum junction temper $_{AS} = -15A$ , $V_{DD} = -50V$ , $R_G = 25 \Omega$ , starting $T_J = 25^{\circ}C$ $Ji/dt \le 300A/\mu s$ , $V_{DD} \le BV_{DSS}$ starting $T_J = 25^{\circ}C$ . Independent of operating temperature.	V <sub>GS</sub> = 0 V, I <sub>S</sub> = -15 A, dI <sub>F</sub> / dt = 100 A/μs ature.		126 0.61		n

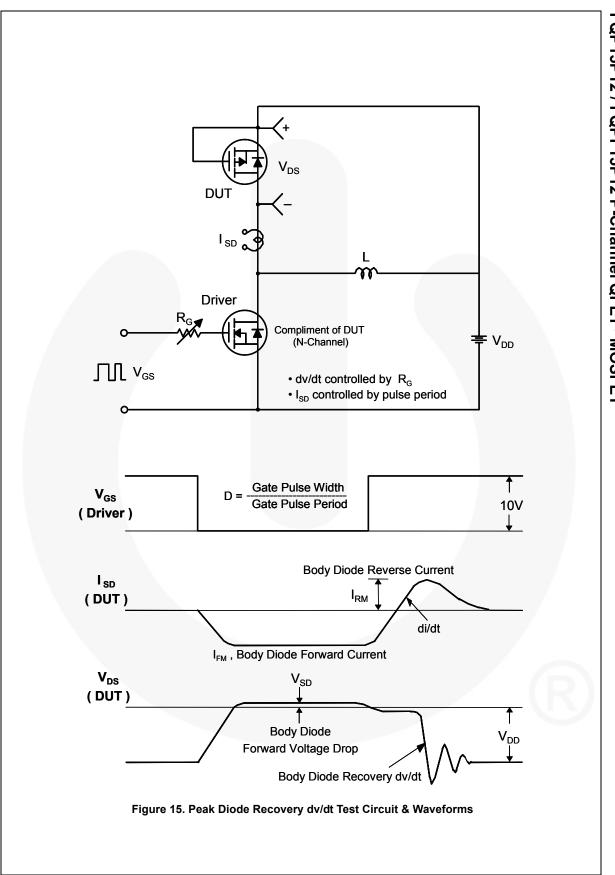


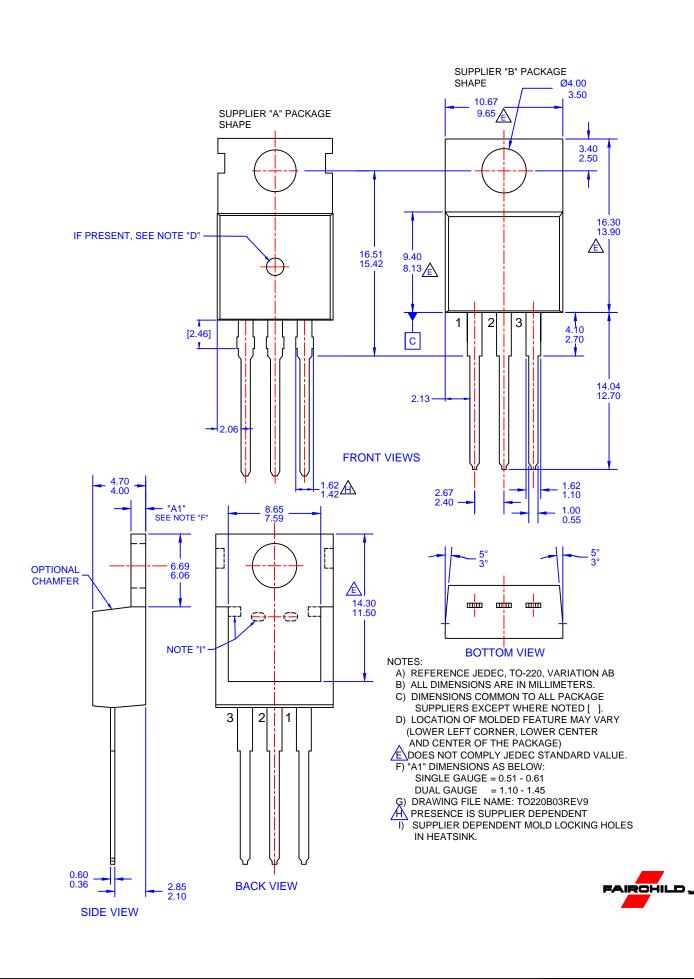
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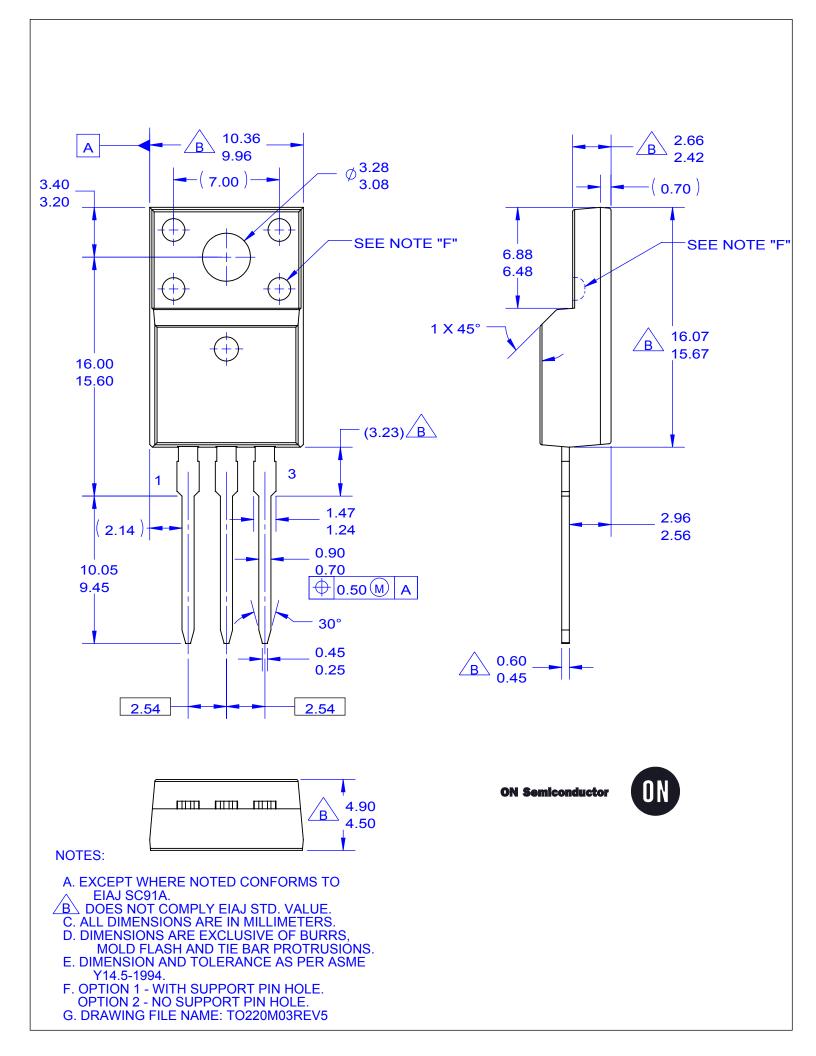












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